

Schottky Barrier project

2021

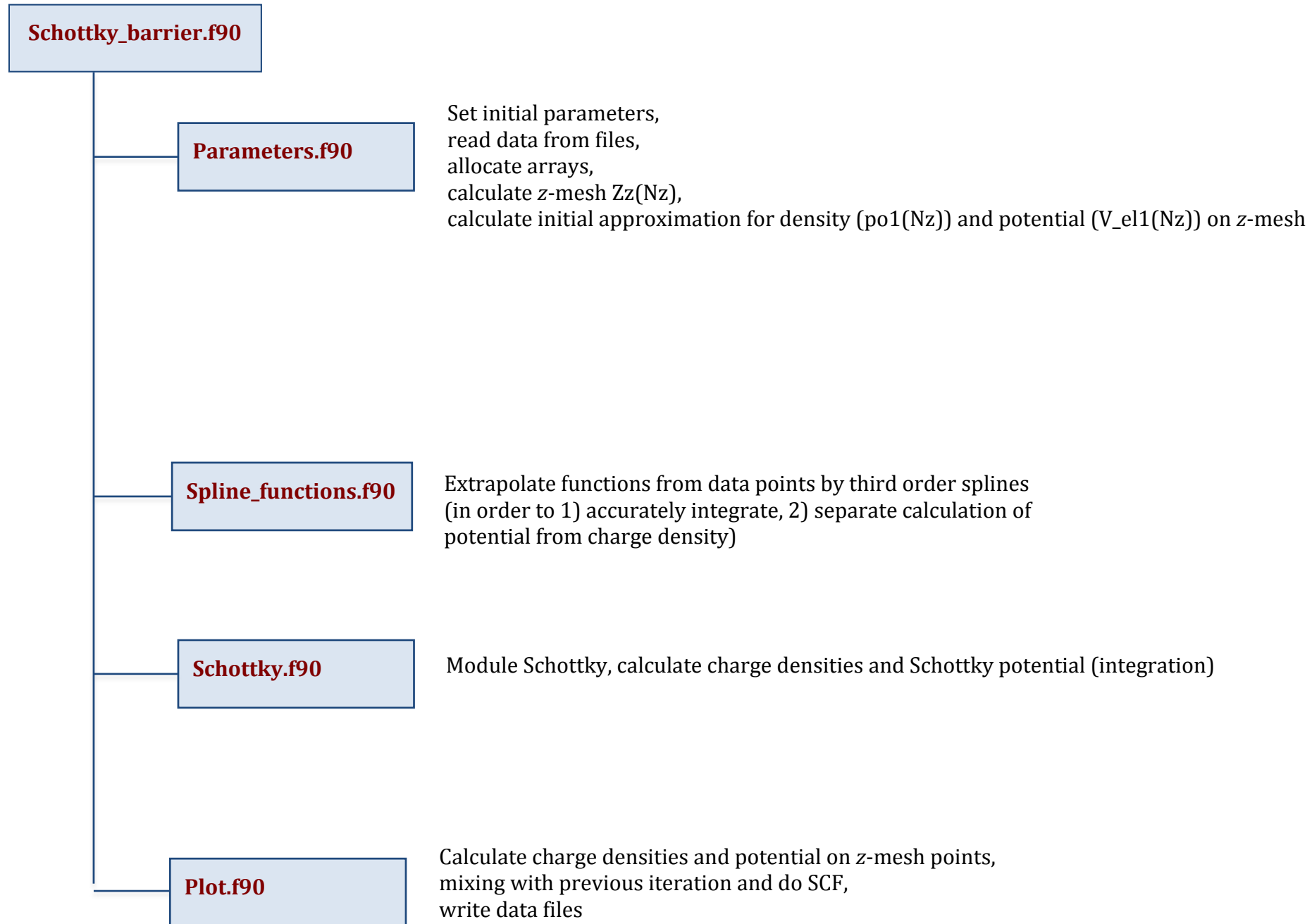
Dmitry Skachkov

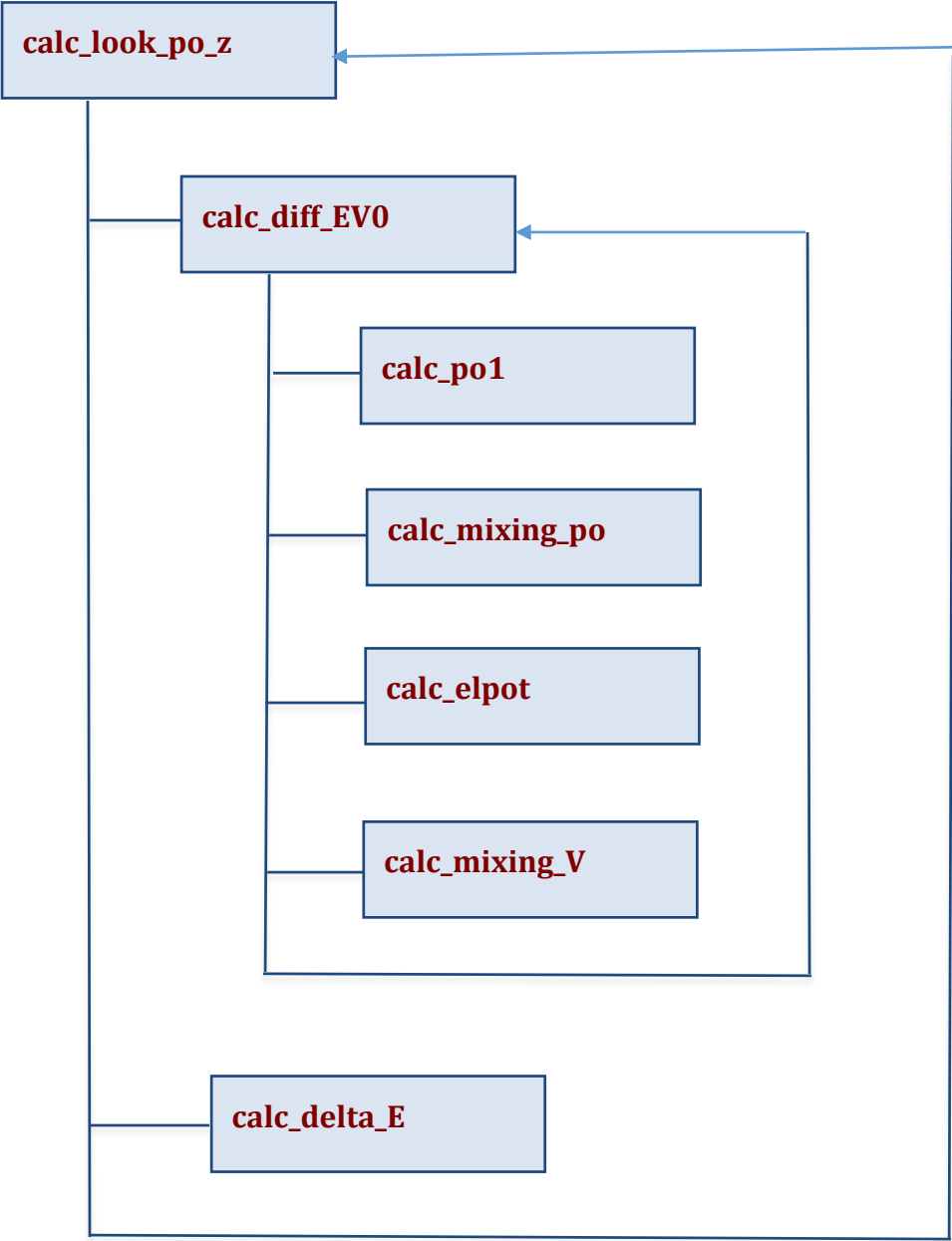
Center for Molecular Magnetic Quantum Materials (M2QM)

<https://efrc.ufl.edu/>

2021

The structure of SB program





Calculate charge density $\rho(z)$ and potential $V(z)$ self-consistently connected

SCF cycle. Initial approximation to $\rho(z)$ and $V(z)$ are formulas (20) and (22)

Calculate $\rho(z)$ using formulas (12) – (16)

Mixing old and new $\rho(z)$ for next iteration

Calculate $V(z)$ using formulas (8) and (10)

Mixing old and new $V(z)$ for next iteration

Calculate ΔE using formula (18)

Repeat SCF cycle until $\rho(z)$ calculated from $V(z)$ will correspond to the $V(z)$ calculated from $\rho(z)$

Additional modules:

QSL3D.f – subroutine for accurate integration of oscillating function

Parallel.f90 – MPI commands for parallelization over z-mesh points

Input data files:

- 1 DOS of the bulk SC (dos_bulk_.dat)
- 2 PDOS of interfacial layer (3d layer - kpdos_int_3.dat, 4th layer - kpdos_int_4.dat, and surface layer - DOS0.dat)
- 3 CBS data (a set of data files from CBS calculation bands.Si.im1,...)
- 4 k-mesh data (k_mesh.dat)
- 5 Polarization data (polarization.dat)

Prepare calculations:

- 1 DOS of bulk semiconductor
- 2 k-separated PDOS for interface calculations for $N \times N \times 1$ k-mesh
- 3 CBS calculation for k-mesh corresponding to interface calculation

Compile the program:

```
> ./compile_mpi.sh
```

To run the program:

```
> schottky 300. 1.35 0. > output  
      T      EF  gate
```

The calculated results:

1 data file for densities po_.dat (in the format of z, poh, poe, poMIGS, po)

2 data file for potential elpot_.dat (in the format of z, V_{el}, E_{field})

3 output file contains all Schottky barrier parameters